

T495B226K010ATE400

General Information

Series

Style

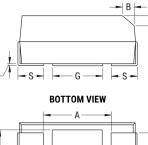
Dielectric

T495, Tantalum, MnO2 Tantalum, 22 uF, 10%, 10 VDC, SMD, MnO2, Molded, Low ESR, 400 mOhms, 3528, Height Max = 2.1mm

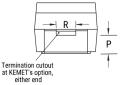
CATHODE (-) END VIEW

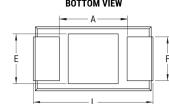


ANODE (+) END VIEW



SIDE VIEW





Click here for the 3D model.

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +0.1/-0.3mm
F	2.2mm +/-0.1mm
А	1.9mm MIN
В	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
Р	0.5mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

Т

Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	107.45 mg
Shelf Life	156 Weeks
MSL	1
Specifications	

T495

SMD Chip

MnO2 Tantalum

specifications	
Capacitance	22 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
Resistance	400 mOhms (100kHz 25C)
Ripple Current	461 mA (rms, 100kHz 25C), 414.9 mA (rms, 85C), 184.4 mA (rms, 125C)
Leakage Current	2.2 uA (5min 25°C)

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	2000	

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